

PRELIMINARY SPEC

L-483F3C

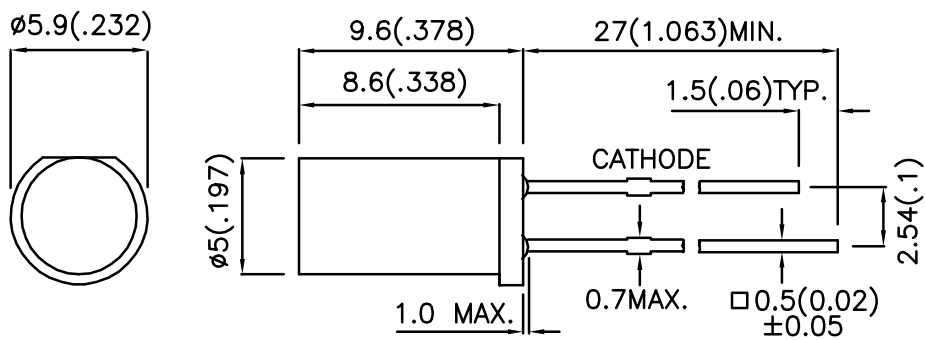
Features

- MECHANICALLY AND SPECTRALLY MATCHED TO THE PHOTOTRANSISTOR.
- WATER CLEAR LENS.

Description

F3 Made with Gallium Arsenide Infrared Emitting diodes.

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25 (0.01)$ unless otherwise noted.
3. Lead spacing is measured where the lead emerge package.
4. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Po (mW/sr) @ 20mA		Viewing Angle
			Min.	Typ.	2θ1/2
L-483F3C	GaAs	WATER CLEAR	2.6	8	80°

Note:

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

Electrical / Optical Characteristics at TA=25°C

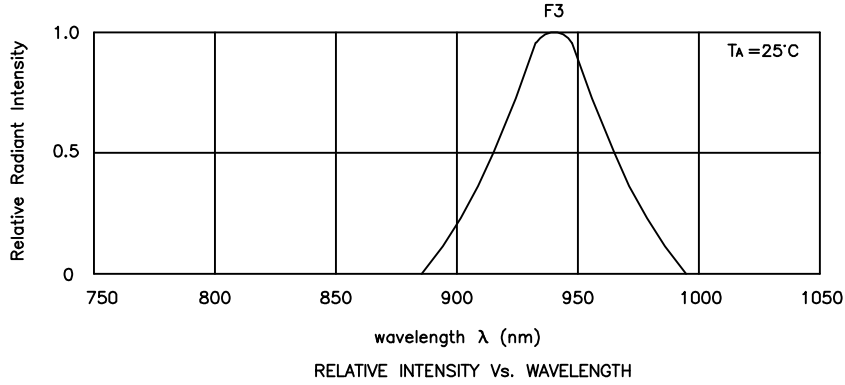
Item	P/N	Symbol	Typ.	Max.	Units	Test Conditions
Forward Voltage	F3	V _F	1.2	1.6	V	I _F =20mA
Reverse Current	F3	I _R	-	10	uA	V _R =5V
Capacitance	F3	C	90	-	pF	V _F =0V;f=1MHz
Peak Spectral Wavelength	F3	λ _P	940	-	nm	I _F =20mA
Spectral Bandwidth	F3	Δλ _{1/2}	50	-	nm	I _F =20mA

Absolute Maximum Ratings at TA=25°C

Parameter	Symbol	F3	Units
Power Dissipation	P _T	100	mW
DC Forward Current	I _F	50	mA
Peak Forward Current[1]	i _{FS}	1.2	A
Reverse Voltage	V _R	5	V
Operating Temperature	T _A	-40 To +85	°C
Storage Temperature	T _{STG}	-40 To +85	°C
Lead Solder Temperature [2]	260°C For 3 Seconds		
Lead Solder Temperature [3]	260°C For 5 Seconds		

Notes:

- 1/100 Duty Cycle, 10μs Pulse Width.
- 2mm below package base.
- 5mm below package base.



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